

ISL32610E, ISL32611E, ISL32612E

±16.5kV ESD Protected, 1.8V, Micro Power, +125°C, 1/8 Unit Load, RS-485/RS-422 Differential Receivers

FN7869
Rev 0.00
October 21, 2011

The ISL32610E, ISL32611E, ISL32612E are ±16.5kV IEC61000 ESD protected, fractional unit load (UL), 1.8V powered, single differential receivers (Rx) for balanced (e.g., RS-485) data communication. With their 85µA supply currents, these receivers are optimized for low power applications, and deliver the lowest supply currents of any available single Rx IC (see Figure 1).

To improve performance in low data rate applications with slow signal transitions, these Rx feature symmetrical switching points (±200mV) and increased hysteresis. The symmetrical switching points eliminate the duty cycle distortion introduced by “full-failsafe” type receivers (see Figure 2), while the larger hysteresis increases noise immunity.

Receivers present a 1/8 “unit load” to the data bus, which allows up to 256 devices on the network for large node count systems (e.g., process automation, remote meter reading systems). The ISL32611E/ISL32612E Rx output is tri-statable via the RE/RE input.

Receiver inputs feature a “failsafe-if-open” design, which ensures a logic high Rx output if Rx inputs are floating. Data rates up to 256kbps are achievable with this device at V_{CC} = 1.8V.

See Table 1 for a summary of each device’s features. For a companion 1.8V differential transmitter in a SOT-23 package, reference the [ISL32613E](#) data sheet.

Features

- Wide Supply Voltage Range 1.8V to 3.6V
- Ultra Low Quiescent Supply Current 110µA (Max.)
- IEC61000 ESD Protection on RS-485 Bus Pins ±16.5kV
- Class 3 ESD Level on all Other Pins >8kV HBM
- Symmetrical Switching Thresholds for Less Duty Cycle Distortion (see Figure 2)
- Larger Hysteresis for Improved Noise Immunity 70mV
- Data Rates up to 256kbps (1.8V) or 500kbps (3.3V)
- 1/8 Unit Load Allows up to 256 Devices on the RS-485 Bus
- Specified for +125°C Operation
- Three State Rx Output Available
- 5V Tolerant Logic Inputs
- Pb-Free (RoHS Compliant)

Applications

- Industrial/Process Control Networks, Factory Automation
- High Node Count Networks
- Space Constrained Systems
- Building Environmental Control Systems

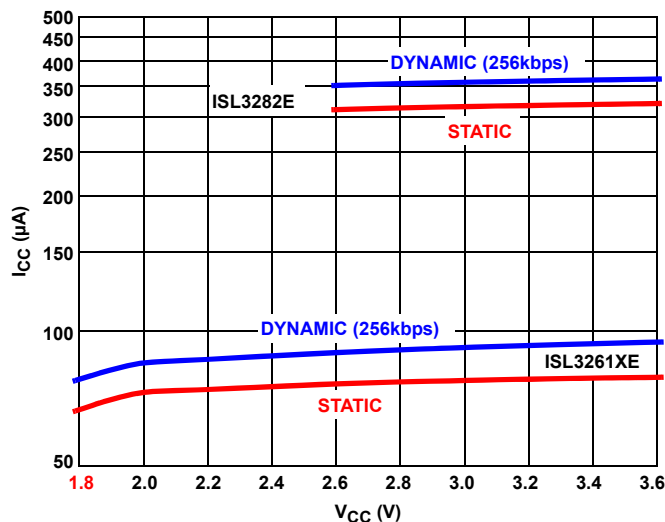


FIGURE 1. ISL3261XE REDUCES OPERATING I_{CC} BY A FACTOR OF 4 FROM PREVIOUS GENERATION RECEIVER ICs, AND OPERATES WITH SUPPLY VOLTAGES AS LOW AS 1.8V

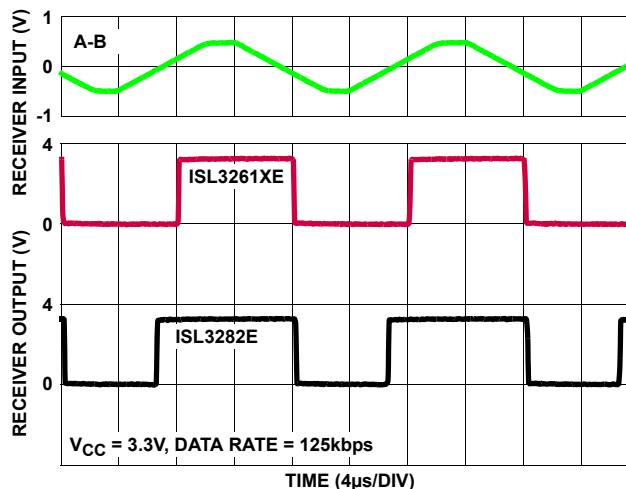


FIGURE 2. COMPARED WITH A FULL-FAILSAFE RECEIVER, THE SYMMETRICAL RX THRESHOLDS OF THE ISL3261XE DELIVER LESS OUTPUT DUTY CYCLE DISTORTION WHEN DRIVEN WITH SLOW INPUT SIGNALS

TABLE 1. SUMMARY OF FEATURES

PART NUMBER	CONFIGURATION	NO. OF DEVICES ALLOWED ON BUS	1.8V, 3.3V DATA RATE (kbps)	Rx ENABLE?	QUIESCENT I _{CC} (μA)	LOW POWER SHUTDOWN?	PIN COUNT
ISL32610E	Rx Only	256	256, 500	No	85	No	5
ISL32611E	Rx Only	256	256, 500	Yes, Active Low	85	Yes	6
ISL32612E	Rx Only	256	256, 500	Yes, Active High	85	Yes	6

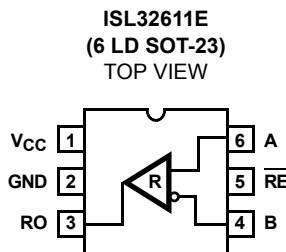
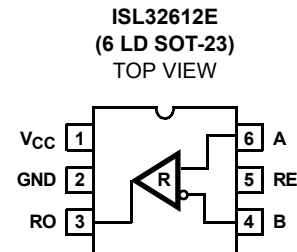
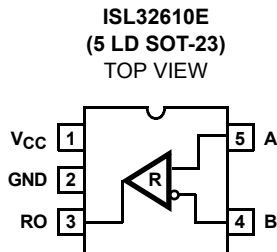
Ordering Information

PART NUMBER (Notes 1, 2, 3, 4)	PART MARKING	TEMP. RANGE (°C)	PACKAGE Tape & Reel (Pb-Free)	PKG. DWG. #
ISL32610EFHZ-T	610F	-40 to +125	5 Ld SOT-23	P5.064
ISL32610EFHZ-T7A	610F	-40 to +125	5 Ld SOT-23	P5.064
ISL32611EFHZ-T	611F	-40 to +125	6 Ld SOT-23	P6.064
ISL32611EFHZ-T7A	611F	-40 to +125	6 Ld SOT-23	P6.064
ISL32612EFHZ-T	612F	-40 to +125	6 Ld SOT-23	P6.064
ISL32612EFHZ-T7A	612F	-40 to +125	6 Ld SOT-23	P6.064

NOTES:

1. Please refer to [TB347](#) for details on reel specifications.
2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials, and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
3. For Moisture Sensitivity Level (MSL), please see device information page for [ISL32610E](#), [ISL32611E](#), [ISL32612E](#). For more information on MSL, please see Tech Brief [TB363](#).
4. The part marking is located on the bottom of the part.

Pin Configurations



Truth Table

RECEIVING		
INPUTS		OUTPUT
\overline{RE} / RE (Note 12)	A-B	RO
0 / 1	$\geq +0.2V$	1
0 / 1	$\leq -0.2V$	0
0 / 1	Inputs Open	1
1 / 0	X	High-Z (Note 5)

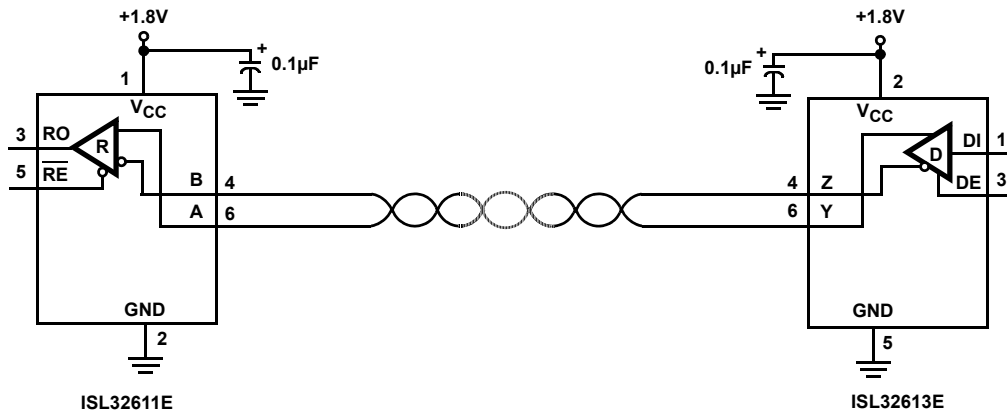
NOTE:

5. Low Power Shutdown Mode (Note 10, except for the ISL32610E)

Pin Descriptions

PIN NAME	PIN NUMBER			FUNCTION
	ISL32610E	ISL32611E	ISL32612E	
V _{CC}	1	1	1	System power supply input (1.8V to 3.6V).
GND	2	2	2	Ground connection.
RO	3	3	3	Receiver output: If A > B by at least 0.2V, RO is high; if A < B by 0.2V or more, RO is low; RO = High if A and B are unconnected (floating).
B	4	4	4	±16.5kV IEC61000 ESD Protected, inverting differential receiver input.
\overline{RE}	-	5	-	Receiver output enable. RO is enabled when \overline{RE} is low; RO is high impedance when \overline{RE} is high. If the enable function isn't needed, connect \overline{RE} to GND. \overline{RE} is internally pulled low.
RE	-	-	5	Receiver output enable. RO is enabled when RE is high; RO is high impedance when RE is low. If the enable function isn't needed, connect RE to V _{CC} through a 1kΩ or greater resistor. RE is internally pulled high.
A	5	6	6	±16.5kV IEC61000 ESD Protected, noninverting differential receiver input.

Typical Operating Circuit



Absolute Maximum Ratings

V _{CC} to Ground	7V
Input Voltages	
\overline{RE} , RE	-0.3V to 7V
A, B	-8V to +12.5V
Output Voltages	
RO	-0.3V to (V _{CC} + 0.3V)
ESD Rating	See "Electrical Specifications" Table page 5
Latch-up (per JESD78, Level 2, Class A)	+125°C

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (°C/W)	θ_{JC} (°C/W)
5 Ld SOT-23 Package (Note 6, 7)	190	120
6 Ld SOT-23 Package (Note 6, 7)	177	120
Maximum Junction Temperature (Plastic Package)	+150°C	
Storage Temperature Range	-65°C to +150°C	
Pb-Free Reflow Profile	see link below	
	http://www.intersil.com/pbfree/Pb-FreeReflow.asp	

Recommended Operating Conditions

Temperature	-40°C to +125°C
Supply Voltage	1.8V to 3.3V
Common Mode Input Voltage	
V _{CC} = 1.8V	-2V to +2V
V _{CC} = 3.3V	-7V to +12V

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

NOTES:

- θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air. See Tech Brief [TB379](#) for details.
- For θ_{JC} , the "case temp" location is taken at the package top center.

Electrical Specifications Test Conditions: V_{CC} = 1.8V; Unless Otherwise Specified. Typicals are at V_{CC} = 1.8V, T_A = +25°C. **Boldface limits apply over the operating temperature range, -40°C to +125°C.** (Note 9)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 8)	TYP	MAX (Note 8)	UNITS	
DC CHARACTERISTICS								
Logic Input High Voltage (Note 12)	V _{IH}	\overline{RE} , RE	V _{CC} = 1.8V	Full	1.2	-	V	
			3V ≤ V _{CC} ≤ 3.6V	Full	2	-	V	
Logic Input Low Voltage (Note 12)	V _{IL}	\overline{RE} , RE	V _{CC} = 1.8V	Full	-	0.45	V	
			3V ≤ V _{CC} ≤ 3.6V	Full	-	0.8	V	
Logic Input Current (Note 12)	I _{IN1}	\overline{RE} , RE	V _{CC} = 1.8V	Full	-6	-	μA	
			V _{CC} ≤ 3.6V	Full	-12	-	μA	
Input Current (A, B) (Note 11)	I _{IN2}	V _{CC} = 0V or 1.8V	V _{IN} = 2V	Full	-	60	μA	
			V _{IN} = -2V	Full	-60	-	μA	
		V _{CC} = 0V or 3.6V	V _{IN} = 12V	Full	-	125	μA	
			V _{IN} = -7V	Full	-100	-	μA	
Receiver Differential Threshold Voltage	V _{TH}	-2V ≤ V _{CM} ≤ 2V	V _{CC} = 1.8V	Full	-0.2	-	V	
		-7V ≤ V _{CM} ≤ 12V	3V ≤ V _{CC} ≤ 3.6V	Full	-0.2	-	V	
Receiver Input Hysteresis	ΔV _{TH}	V _{CM} = 0V	V _{CC} = 1.8V	Full	-	70	mV	
			3V ≤ V _{CC} ≤ 3.6V	Full	-	70	mV	
Receiver Output High Voltage	V _{OH}	I _O = -1mA, V _{ID} = 200mV	Full	V_{CC} - 0.4	-	-	V	
Receiver Output Low Voltage	V _{OL}	I _O = 2mA, V _{ID} = -200mV	Full	-	-	0.4	V	
Three-State (High Impedance) Receiver Output Current (Note 12)	I _{OZR}	0V ≤ V _O ≤ V _{CC}	Full	-1	-	1	μA	
Receiver Short-Circuit Current	I _{OSR}	0V ≤ V _O ≤ V _{CC}	Full	-	-	30	mA	
No-Load Supply Current	I _{CC}	\overline{RE} = 0V or RE = V _{CC}	V _{CC} = 1.8V	Full	-	85	μA	
			3V ≤ V _{CC} ≤ 3.6V	Full	-	-	135	μA
Shutdown Supply Current (Notes 10, 12)	I _{SHDN}	ISL32611, \overline{RE} = V _{CC} , V _{CC} ≥ 1.8V	V _{CC} = 1.8V	Full	-	-	2	μA
			V _{CC} ≤ 3.6V	Full	-	-	14	μA
		ISL32612, RE = 0V	V _{CC} = 1.8V	Full	-	-	7	μA

Electrical Specifications Test Conditions: $V_{CC} = 1.8V$; Unless Otherwise Specified. Typicals are at $V_{CC} = 1.8V$, $T_A = +25^\circ C$. **Boldface limits apply over the operating temperature range, $-40^\circ C$ to $+125^\circ C$.** (Note 9) (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	TEMP (°C)	MIN (Note 8)	TYP	MAX (Note 8)	UNITS
SWITCHING CHARACTERISTICS							
Maximum Data Rate	f_{MAX}	$V_{ID} = \pm 1V$, $V_{CM} = 0V$, (Figure 3)	$V_{CC} = 1.8V$	Full	256	-	kbps
			$3V \leq V_{CC} \leq 3.6V$	Full	500	-	kbps
Receiver Input to Output Delay	t_{PLH} , t_{PHL}	(Figure 3)	$V_{CC} = 1.8V$	Full	-	210	1000 ns
			$V_{CC} = 3.3V$	25	-	200	-
Receiver Skew $t_{PLH} - t_{PHL}$	t_{SKD}	(Figure 3)	$V_{CC} = 1.8V$	Full	-	3	125 ns
			$V_{CC} = 3.3V$	25	-	6	-
Receiver Enable to Output High	t_{ZH}	$C_L = 15pF$, SW = GND, (Figure 4, Note 12)	$V_{CC} = 1.8V$	Full	-	1100	4000 ns
			$V_{CC} = 3.3V$	25	-	1500	-
Receiver Enable to Output Low	t_{ZL}	$C_L = 15pF$, SW = V_{CC} , (Figure 4, Note 12)	$V_{CC} = 1.8V$	Full	-	1100	4000 ns
			$V_{CC} = 3.3V$	25	-	1500	-
Receiver Disable from Output High	t_{HZ}	$C_L = 15pF$, SW = GND, (Figure 4, Note 12)	$V_{CC} = 1.8V$	Full	-	15	75 ns
			$V_{CC} = 3.3V$	25	-	6	-
Receiver Disable from Output Low	t_{LZ}	$C_L = 15pF$, SW = V_{CC} , (Figure 4, Note 12)	$V_{CC} = 1.8V$	Full	-	15	75 ns
			$V_{CC} = 3.3V$	25	-	6	-
ESD PERFORMANCE							
RS-485 Pins (A, B)		IEC61000-4-2, Air-Gap Discharge Method	25	-	± 16.5	-	kV
		IEC61000-4-2, Contact Discharge Method	25	-	± 9	-	kV
		Human Body Model, From Bus Pins to GND	25	-	± 16.5	-	kV
All Pins		Human Body Model (Tested per JESD22-A114E)	25	-	± 8	-	kV
		Machine Model (Tested per JESD22-A115-A)	25	-	± 400	-	V

NOTES:

- 8. Compliance to data sheet limits is assured by one or more methods: production test, characterization and/or design.
- 9. Currents into device pins are positive; currents out of device pins are negative. Voltages are referenced to ground unless otherwise specified.
- 10. The ISL32611E enters SHDN whenever \overline{RE} switches high, and the ISL32612E enters SHDN whenever RE switches low.
- 11. Devices meeting these limits are denoted as "1/8 unit load (1/8 UL)" transceivers. The RS-485 standard allows up to 32 Unit Loads on the bus, so there can be 256 1/8 UL devices on a bus.
- 12. Not applicable to the ISL32610E.

Test Circuits and Waveforms

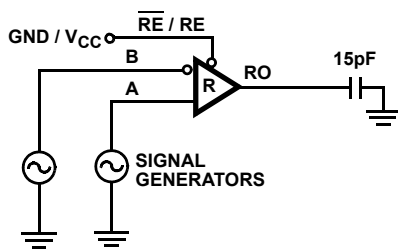


FIGURE 3A. TEST CIRCUIT

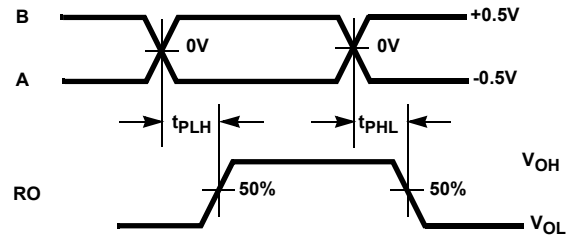
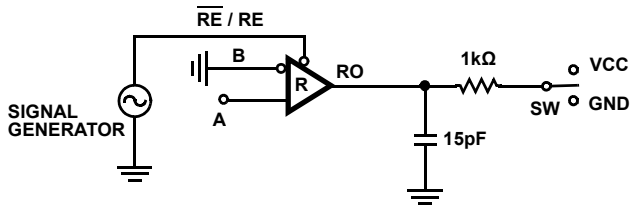


FIGURE 3B. MEASUREMENT POINTS

FIGURE 3. RECEIVER PROPAGATION DELAY AND DATA RATE

Test Circuits and Waveforms (Continued)



PARAMETER	A	SW
t_{HZ}	+1V	GND
t_{LZ}	-1V	V_{CC}
t_{ZH}	+1V	GND
t_{ZL}	-1V	V_{CC}

FIGURE 4A. TEST CIRCUIT

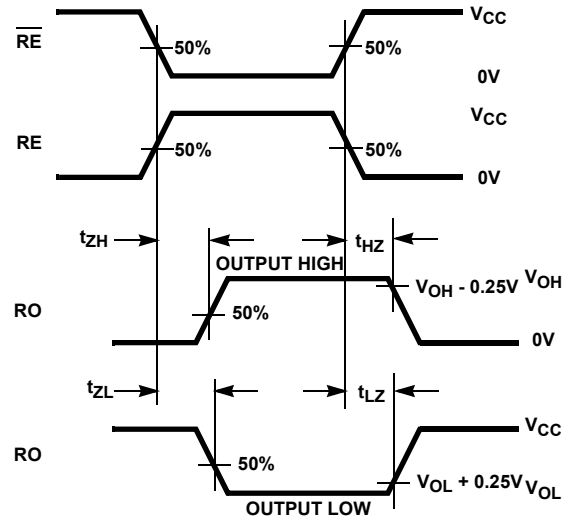


FIGURE 4B. MEASUREMENT POINTS

FIGURE 4. RECEIVER ENABLE AND DISABLE TIMES (EXCLUDING ISL32610E)

Application Information

Features

These devices utilize a differential input receiver for maximum noise immunity and common mode rejection. Input sensitivity is $\pm 200\text{mV}$, as required by the RS-422 and RS-485 standards. These receivers' symmetrical $\pm 200\text{mV}$ switching thresholds deliver less duty cycle distortion than similar receivers with a full-failsafe design (i.e., skewed low/high input thresholds, (such as $-200\text{mV}/-20\text{mV}$) which increase the high bit width). This distortion is especially noticeable when the Rx is driven by slow input transitions (see Figure 2).

The symmetrical input thresholds also allow more room for increased input hysteresis, thereby increasing the Rx noise immunity. The 70mV hysteresis of this Rx is twice the amount specified for most full-failsafe devices.

Receiver input resistance of $96\text{k}\Omega$ surpasses the RS-422 specification of $4\text{k}\Omega$, and is eight times the RS-485 "Unit Load (UL)" requirement of $12\text{k}\Omega$ minimum. Thus, these products are known as "one-eighth UL" receivers, and there can be up to 256 of these devices on a network while still complying with the RS-485 loading specification.

Receiver inputs function with common mode voltages (CMV) of $\pm 2\text{V}$ with $V_{\text{CC}} = 1.8\text{V}$, and with CMVs of -7V to $+12\text{V}$ for $V_{\text{CC}} \geq 2.7\text{V}$.

All the receivers include a "failsafe-if-open" function that guarantees a high level receiver output if the receiver inputs are unconnected (floating). As mentioned previously, the full-failsafe function is not implemented in order to deliver output duty cycles that better match the input.

Receivers support data rates up to 256kbps ($V_{\text{CC}} = 1.8\text{V}$) or 500kbps ($V_{\text{CC}} \geq 3\text{V}$), and receiver outputs of the ISL32611E and ISL32612E are three-statable via the active low $\overline{\text{RE}}$ or active high RE input.

Data Rate Recommendations

When coupled with the ISL32613E or ISL32614E 1.8V transmitter ICs, these receivers are useful for networks up to $4000'$ (1220m) long, or for data rates up to 500kbps . For $4000'$ distances with $V_{\text{CC}} = 1.8\text{V}$, the ISL32613E can be used with any of these receivers at data rates $\leq 50\text{kbps}$. With $V_{\text{CC}} = 3.3\text{V}$, any transmitter / receiver combination operates over $4000'$ at rates up to 128kbps . Shorter networks allow data rates up to 500kbps , as shown in Figures 9, 10, 11 and 12.

Network termination resistors are only recommended for networks operating at $V_{\text{CC}} \geq 2.7\text{V}$, and using termination resistors may allow for higher data rates.

Low Power Shutdown Mode (ISL32611E and ISL32612E)

These devices use a fraction of the power required by most differential receivers (see Figure 1 on page 1), but they also include a shutdown feature that reduces the already low quiescent I_{CC} even further. The ISL32611E and ISL32612E enter shutdown whenever the receiver is disabled ($\text{RE} = \text{GND}$ or $\overline{\text{RE}} = V_{\text{CC}}$).

ESD Protection

All pins on these devices include class 3 ($>6\text{kV}$) Human Body Model (HBM) ESD protection structures, but the bus pins (Rx inputs) incorporate advanced structures allowing them to survive ESD events in excess of $\pm 16.5\text{kV}$ HBM and $\pm 16.5\text{kV}$ IEC61000. The bus pins are particularly vulnerable to ESD damage because they typically connect to an exposed port on the exterior of the finished product. Simply touching the port pins, or connecting a cable, can cause an ESD event that might destroy unprotected ICs. These new ESD structures protect the device whether or not it is powered up, and without degrading the common mode range. This built-in ESD protection eliminates the need for board-level protection structures (e.g., transient suppression diodes), and the associated, undesirable capacitive load they present.

IEC61000-4-2 Testing

The IEC61000 test method applies to finished equipment, rather than to an individual IC. Therefore, the pins most likely to suffer an ESD event are those that are exposed to the outside world (the bus pins in this case), and the IC is tested in its typical application configuration (power applied) rather than testing each pin-to-pin combination. The smaller value current limiting resistor coupled with the larger charge storage capacitor yields a test that is much more severe than the HBM test. The extra ESD protection built into this device's bus pins allows the design of equipment meeting level 4 criteria without the need for additional board-level protection on the I/O port.

AIR-GAP DISCHARGE TEST METHOD

For the air-gap discharge test method, a charged probe tip moves toward the IC pin until the voltage arcs to it. The current waveform delivered to the IC pin depends on approach speed, humidity, temperature, etc., so it is difficult to obtain repeatable results. The A and B pins withstand $\pm 16.5\text{kV}$ air-gap discharges.

CONTACT DISCHARGE TEST METHOD

During the contact discharge test, the probe contacts the tested pin before the probe tip is energized, thereby eliminating the variables associated with the air-gap discharge. The result is a more repeatable and predictable test, but equipment limits prevent testing devices at voltages higher than $\pm 9\text{kV}$. The ISL32610E, ISL32611E, ISL32612E survive $\pm 9\text{kV}$ contact discharges on the bus pins.

Typical Performance Curves T_A = +25°C; Unless Otherwise Specified

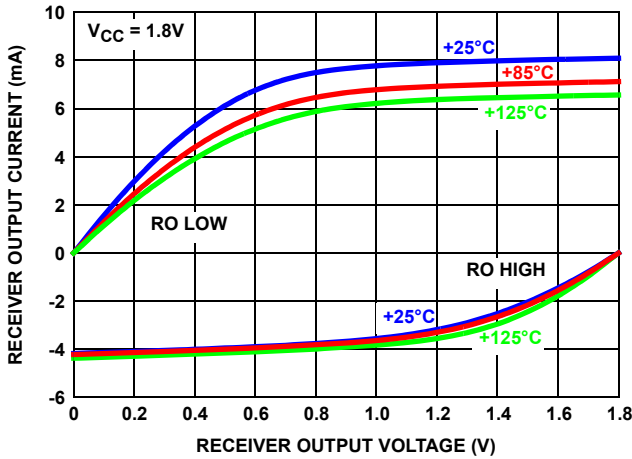


FIGURE 5. RECEIVER OUTPUT CURRENT vs RECEIVER OUTPUT VOLTAGE (V_{CC} = 1.8V)

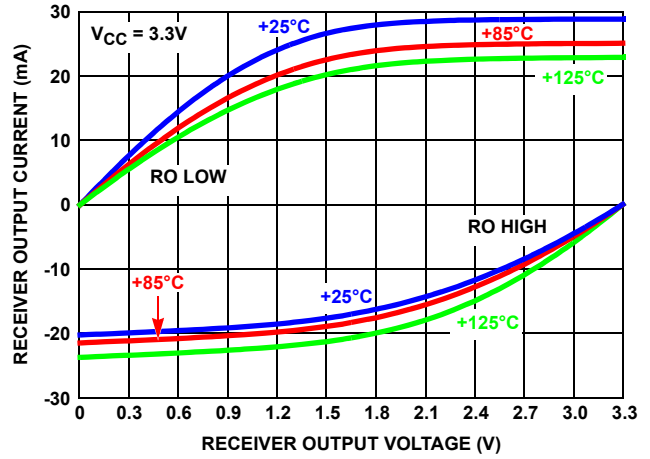


FIGURE 6. RECEIVER OUTPUT CURRENT vs RECEIVER OUTPUT VOLTAGE (V_{CC} = 3.3V)

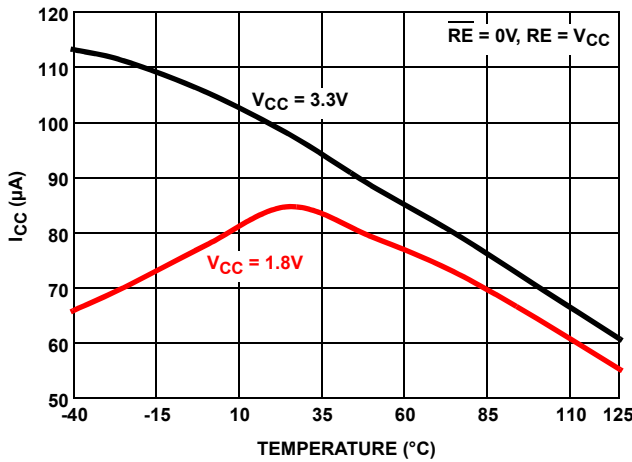


FIGURE 7. STATIC SUPPLY CURRENT vs TEMPERATURE

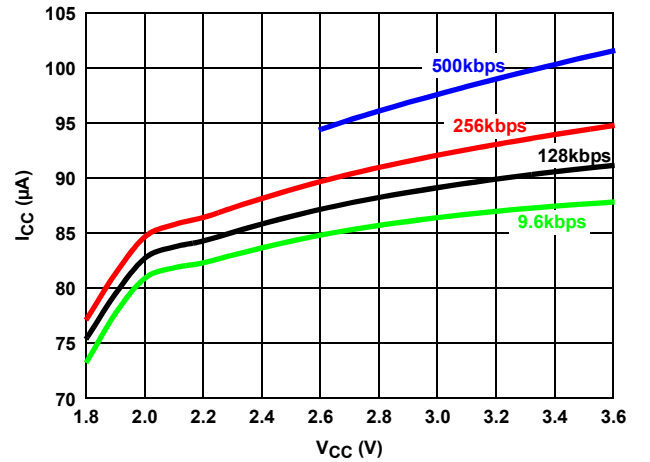


FIGURE 8. DYNAMIC SUPPLY CURRENT vs SUPPLY VOLTAGE AT DIFFERENT DATA RATES

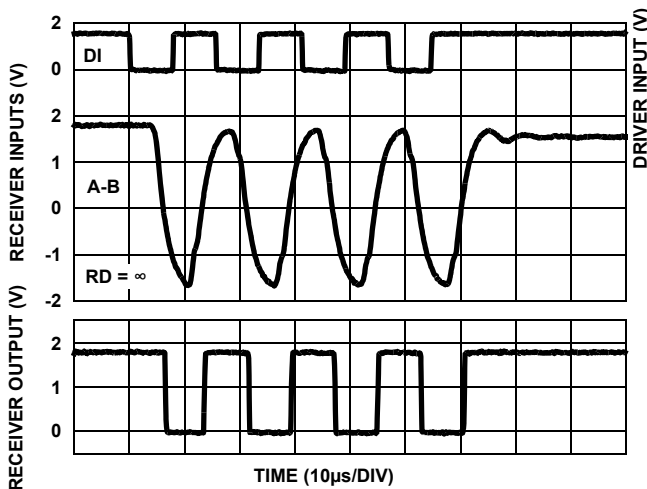


FIGURE 9. ISL32613E AND ISL32611E PERFORMANCE WITH V_{CC} = 1.8V, 128kbps, 2000' (610m) CAT 5 CABLE

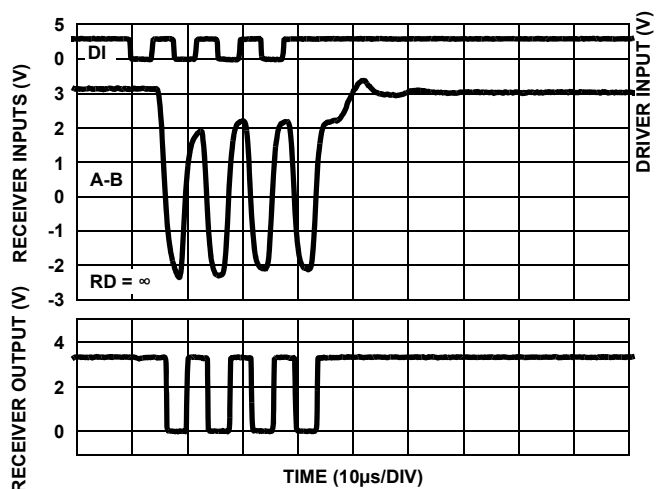


FIGURE 10. ISL32613E AND ISL32611E PERFORMANCE WITH V_{CC} = 3.3V, 256kbps, 3000' (915m) CAT 5 CABLE

Typical Performance Curves $T_A = +25^\circ\text{C}$; Unless Otherwise Specified (Continued)

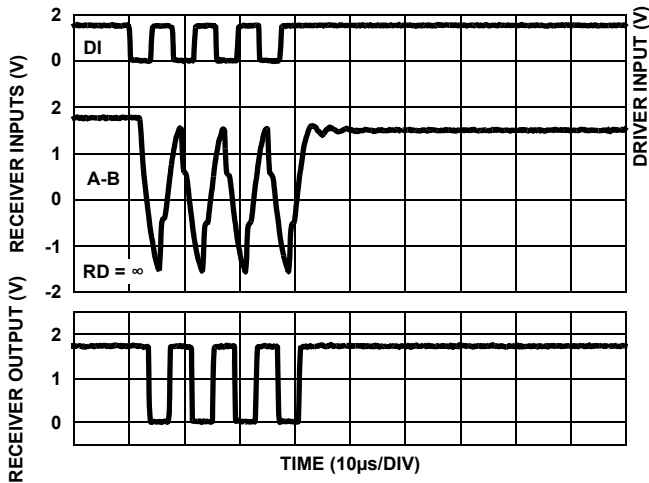


FIGURE 11. ISL32614E AND ISL32611E PERFORMANCE WITH $V_{CC} = 1.8\text{V}$, 256kbps, 1000' (305m) CAT 5 CABLE

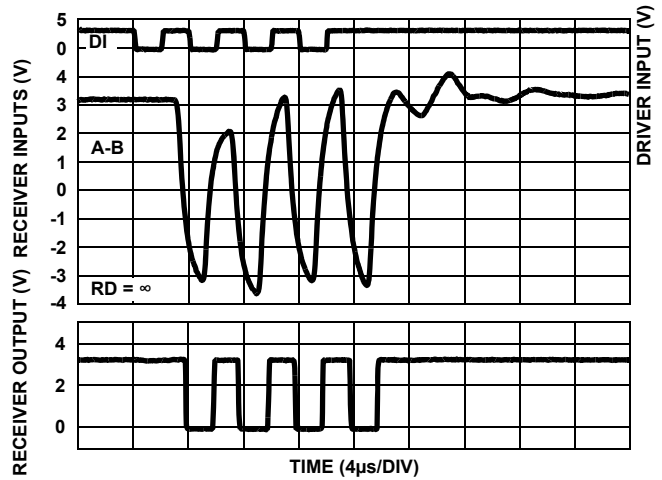


FIGURE 12. ISL32614E AND ISL32611E PERFORMANCE WITH $V_{CC} = 3.3\text{V}$, 500kbps, 2000' (610m) CAT 5 CABLE

Die Characteristics

SUBSTRATE POTENTIAL (POWERED UP) :

GND

PROCESS:

Si Gate BiCMOS

Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

DATE	REVISION	CHANGE
10/21/2011	FN7869.0	Initial Release

Products

Intersil Corporation is a leader in the design and manufacture of high-performance analog semiconductors. The Company's products address some of the industry's fastest growing markets, such as, flat panel displays, cell phones, handheld products, and notebooks. Intersil's product families address power management and analog signal processing functions. Go to www.intersil.com/products for a complete list of Intersil product families.

For a complete listing of Applications, Related Documentation and Related Parts, please see the respective device information page on intersil.com: [ISL32610E](#), [ISL32611E](#), [ISL32612E](#)

To report errors or suggestions for this datasheet, please go to: www.intersil.com/askourstaff

FITs are available from our website at: <http://rel.intersil.com/reports/search.php>

© Copyright Intersil Americas LLC 2011. All Rights Reserved.

All trademarks and registered trademarks are the property of their respective owners.

For additional products, see www.intersil.com/en/products.html

Intersil products are manufactured, assembled and tested utilizing ISO9001 quality systems as noted in the quality certifications found at www.intersil.com/en/support/qualandreliability.html

Intersil products are sold by description only. Intersil may modify the circuit design and/or specifications of products at any time without notice, provided that such modification does not, in Intersil's sole judgment, affect the form, fit or function of the product. Accordingly, the reader is cautioned to verify that datasheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.

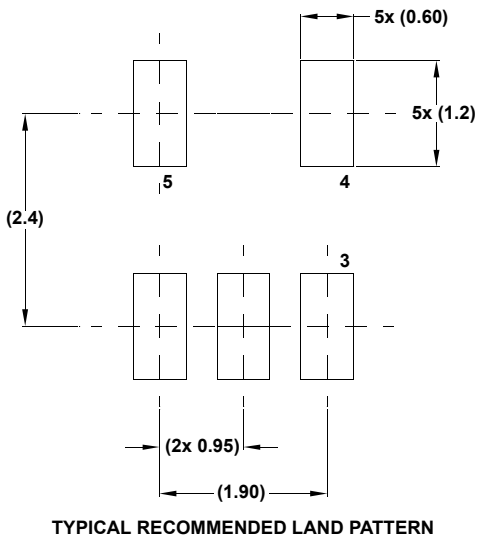
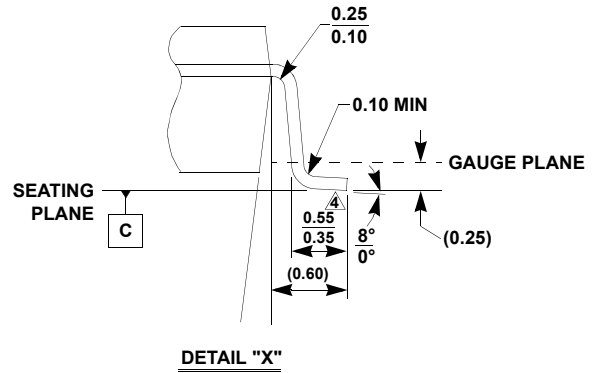
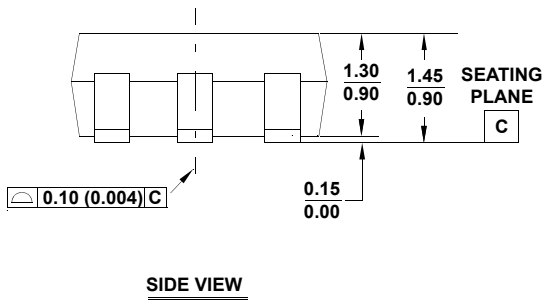
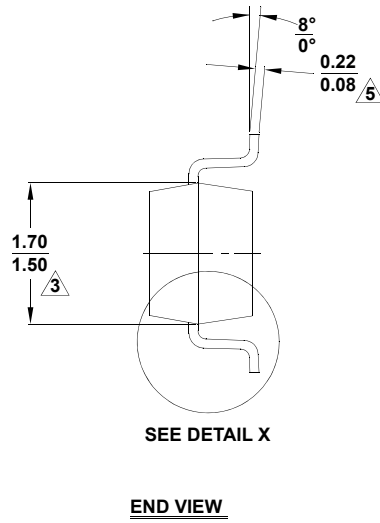
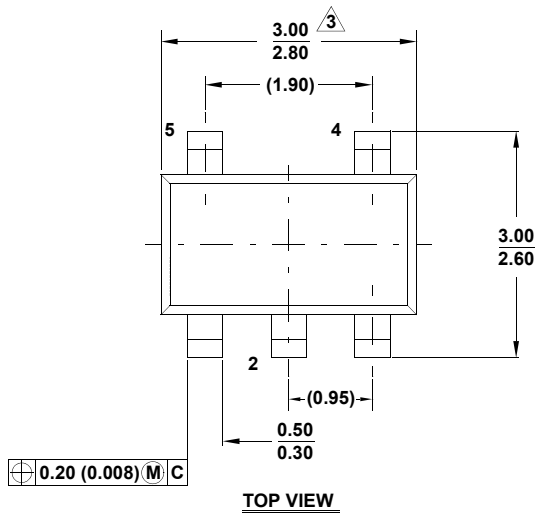
For information regarding Intersil Corporation and its products, see www.intersil.com

Package Outline Drawing

P5.064

5 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE

Rev 3, 4/11



NOTES:

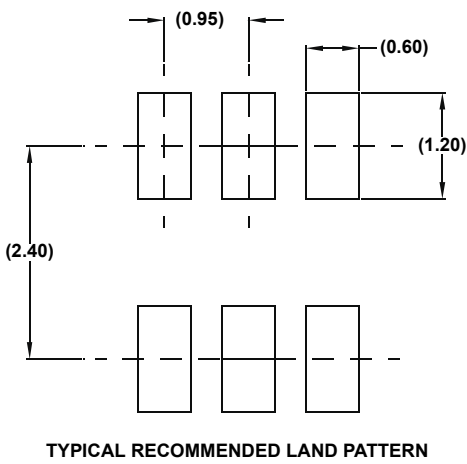
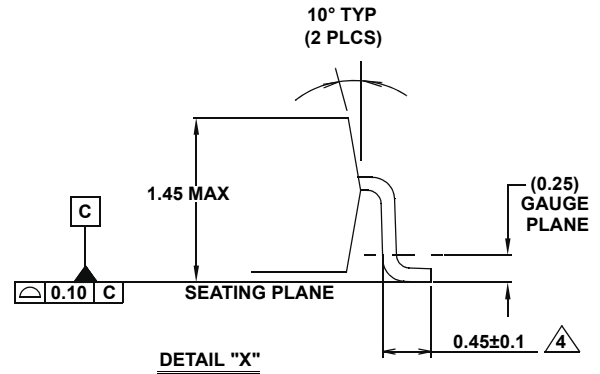
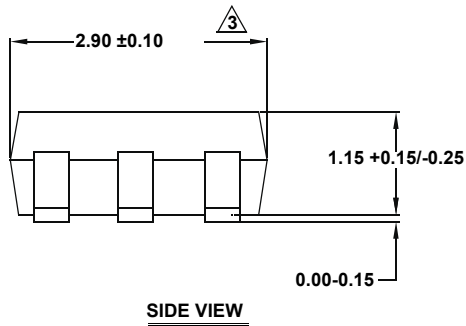
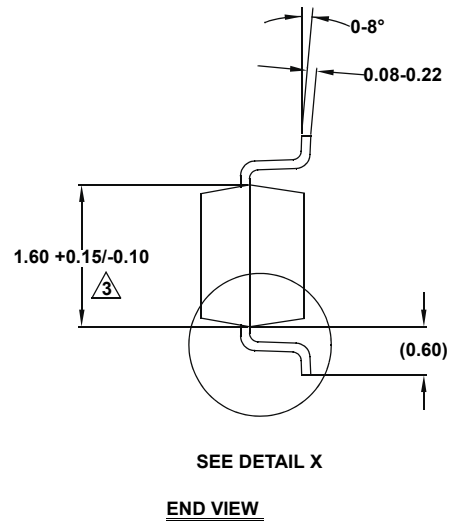
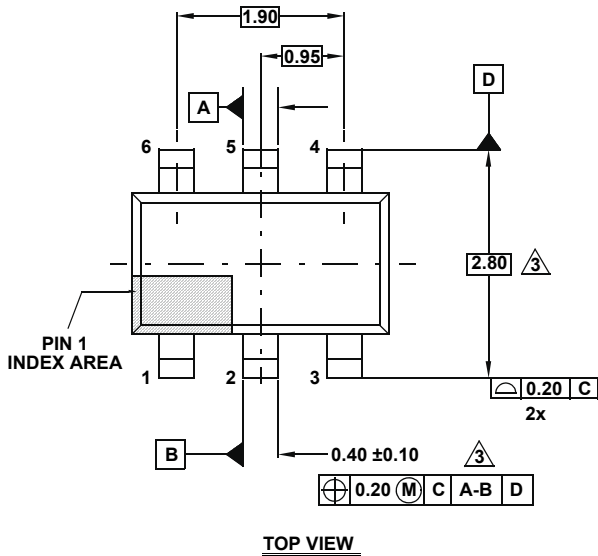
1. Dimensioning and tolerance per ASME Y14.5M-1994.
2. Package conforms to EIAJ SC-74 and JEDEC MO178AA.
3. Package length and width are exclusive of mold flash, protrusions, or gate burrs.
4. Footlength measured at reference to gauge plane.
5. Lead thickness applies to the flat section of the lead between 0.08mm and 0.15mm from the lead tip.
6. Controlling dimension: MILLIMETER.
Dimensions in () for reference only.

Package Outline Drawing

P6.064

6 LEAD SMALL OUTLINE TRANSISTOR PLASTIC PACKAGE

Rev 4, 2/10



NOTES:

1. Dimensions are in millimeters.
Dimensions in () for Reference Only.
2. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
3. Dimension is exclusive of mold flash, protrusions or gate burrs.
4. Foot length is measured at reference to gauge plane.
5. Package conforms to JEDEC MO-178AB.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Renesas Electronics:](#)

[ISL32610EFHZ-T](#) [ISL32610EFHZ-T7A](#) [ISL32611EFHZ-T](#) [ISL32611EFHZ-T7A](#) [ISL32612EFHZ-T](#) [ISL32612EFHZ-T7A](#)